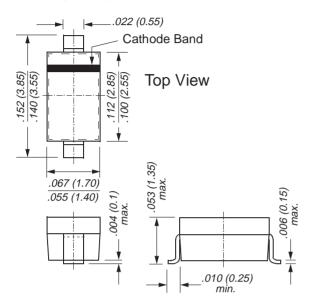


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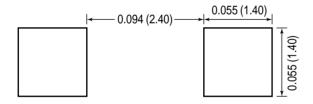


Tuner Diodes

SOD-123 (BB731)



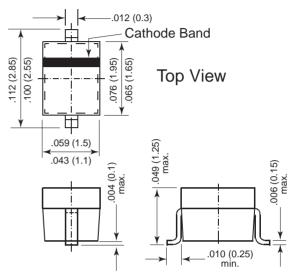
Mounting Pad Layout SOD-123 (BB731)



Features

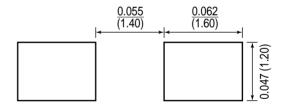
- Silicon epitaxial planar capacitance diodes with very wide effective capacitance variation for tuning the VHF range 41 ... 170 MHz in hyperband television tuners.
- These diodes are available as singles or as matched sets of two or more units according to the tracking condition described in the table of characteristics.

SOD-323 (BB731S)



Dimensions in inches and (millimeters)

Mounting Pad Layout SOD-323 (BB731S)



Mechanical Data

Case: BB731 = SOD-123 Plastic Case BB731S = SOD-323 Plastic Case

Weight: BB731 = approx. 0.01g BB731S = approx. 0.004g

Packaging Codes/Options:

SOD-123: D3/10K per 13" reel (8mm tape), 30K/box D4/3K per 7" reel (8mm tape), 30K/box SOD-323: D5/10K per 13" reel (8mm tape), 30K/box D6/3K per 7" reel (8mm tape), 30K/box

Maximum Ratings and Thermal Characteristics (TC = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Reverse Voltage	VR	32	V
Junction Temperature	TJ	125	°C
Storage Temperature Range	Ts	-55 to +125	°C

BB731 and BB731S

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Electrical Characteristics (Tc = 25°C unless otherwise noted)

Parameter	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage at I _R = 100µA	V _{(BR)R}	32	_	_	V
Leakage Current at V _R = 30V	IR	_	-	30	nA
Capacitance $f = 1MH_Z$ at $V_R = 28V$ at $V_R = 25V$ at $V_R = 1V$	Ctot	3.15 - -	- 3.5 50	3.55 - -	pF
Effective Capacitance Ratio f = 1MHz at V _R = 1 to 28V	Ctot (1V) Ctot (28V)	19.5	-	25	_
at $V_R = 3$ to $25V$	Ctot (3V) Ctot (25V)	-	14	-	_
Series Resistance at f = 300 MHz, Ctot = 25 pF	rs	_	0.9	1.0	Ω
Series Inductance	Ls	_	2.5	_	nH

For any two of six consecutive diodes in the carrier tape, the maximum capacitance deviation in the reverse bias voltage of VR = 0.5 to 28V is 3%

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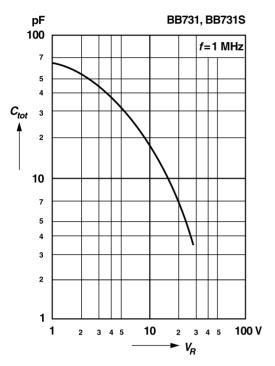




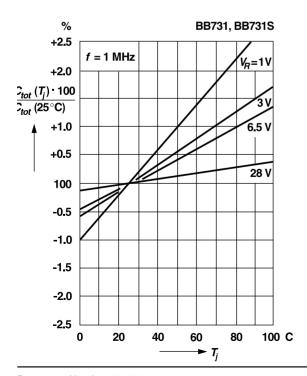
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Ratings and Characteristic Curves (TA = 25°C unless otherwise noted)

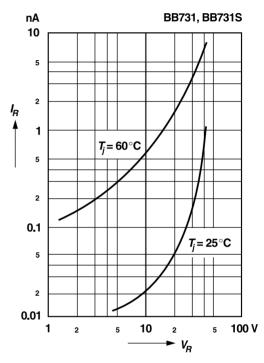
Capacitance versus reverse voltage



Relative capacitance versus junction temperature



Leakage current versus reverse voltage



Q-Factor versus frequency

